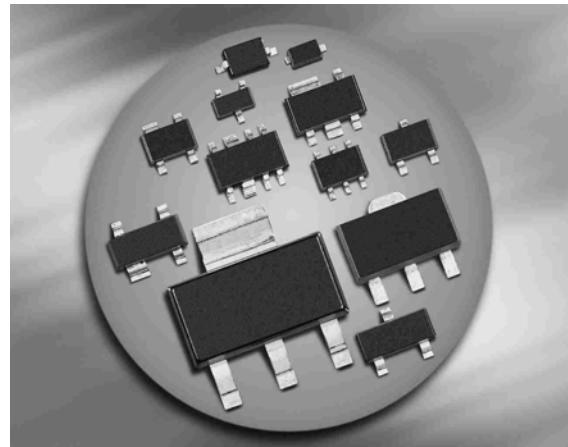
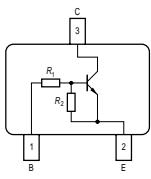


NPN Silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ($R_1=47\text{k}\Omega$, $R_2=22\text{k}\Omega$)



BCR146/F/L3
BCR146T/W



Type	Marking	Pin Configuration						Package
BCR146	WLs	1=B	2=E	3=C	-	-	-	SOT23
BCR146F	WLs	1=B	2=E	3=C	-	-	-	TSFP-3
BCR146L3	WL	1=B	2=E	3=C	-	-	-	TSLP-3-4
BCR146T	WLs	1=B	2=E	3=C	-	-	-	SC75
BCR146W	WLs	1=B	2=E	3=C	-	-	-	SOT323

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}	50	V
Collector-base voltage	V_{CBO}	50	
Emitter-base voltage	V_{EBO}	10	
Input on voltage	$V_{i(on)}$	50	
Collector current	I_C	70	mA
Total power dissipation- BCR146, $T_S \leq 102^\circ\text{C}$	P_{tot}	200	mW
BCR146F, $T_S \leq 128^\circ\text{C}$		250	
BCR146L3, $T_S \leq 135^\circ\text{C}$		250	
BCR146T, $T_S \leq 109^\circ\text{C}$		250	
BCR146W, $T_S \leq 124^\circ\text{C}$		250	
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾ BCR146	R_{thJS}	≤ 240	K/W
BCR146F			
BCR146L3			
BCR146T			
BCR146W			

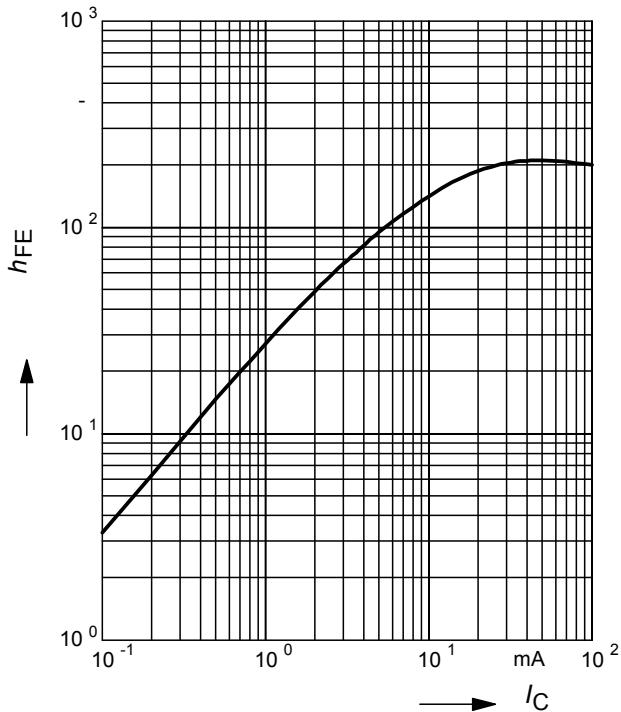
¹For calculation of R_{thJA} please refer to Application Note Thermal Resistance

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

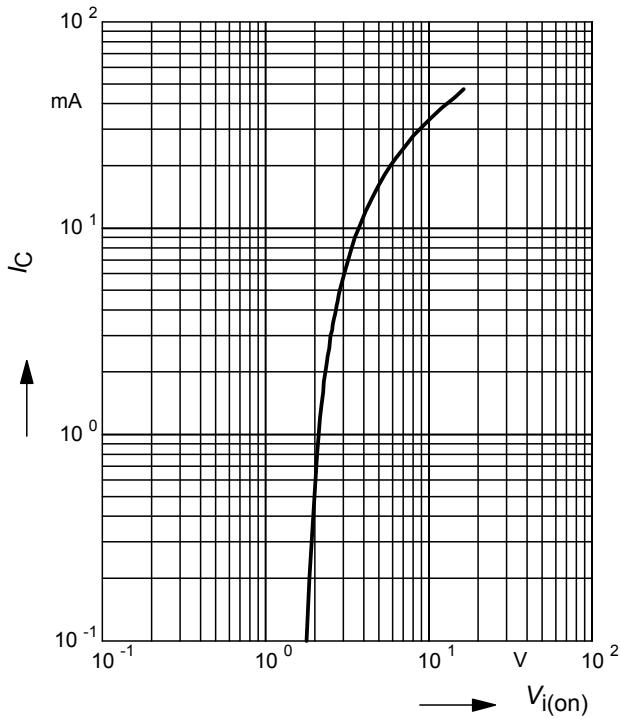
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage $I_C = 100 \mu\text{A}, I_B = 0$	$V_{(\text{BR})\text{CEO}}$	50	-	-	V
Collector-base breakdown voltage $I_C = 10 \mu\text{A}, I_E = 0$	$V_{(\text{BR})\text{CBO}}$	50	-	-	
Collector-base cutoff current $V_{CB} = 40 \text{ V}, I_E = 0$	I_{CBO}	-	-	100	nA
Emitter-base cutoff current $V_{EB} = 10 \text{ V}, I_C = 0$	I_{EBO}	-	-	220	μA
DC current gain ¹⁾ $I_C = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	h_{FE}	50	-	-	-
Collector-emitter saturation voltage ¹⁾ $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$	V_{CEsat}	-	-	0.3	V
Input off voltage $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$	$V_{i(\text{off})}$	1.2	-	2.6	
Input on voltage $I_C = 2 \text{ mA}, V_{CE} = 0.3 \text{ V}$	$V_{i(\text{on})}$	1.5	-	4	
Input resistor	R_1	32	47	62	k Ω
Resistor ratio	R_1/R_2	1.92	2.14	2.36	-
AC Characteristics					
Transition frequency $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}, f = 100 \text{ MHz}$	f_T	-	150	-	MHz
Collector-base capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$	C_{cb}	-	3	-	pF

¹Pulse test: $t < 300\mu\text{s}$; $D < 2\%$

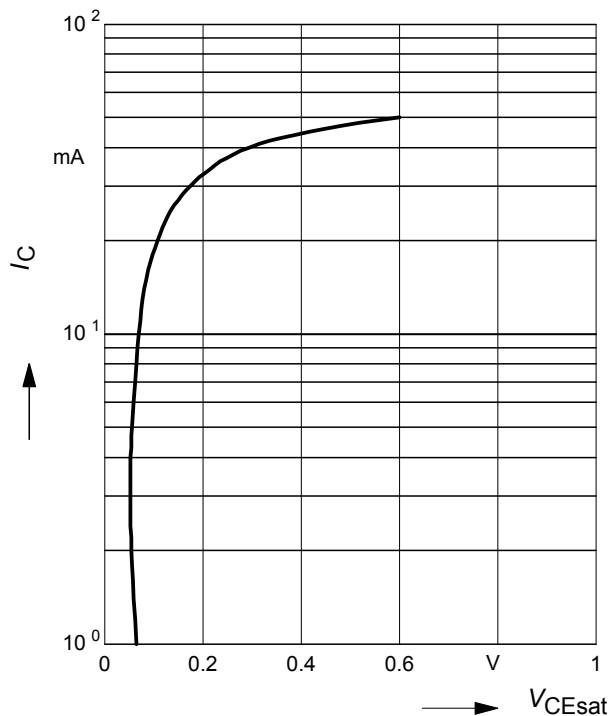
DC current gain $h_{FE} = f(I_C)$
 $V_{CE} = 5V$ (common emitter configuration)



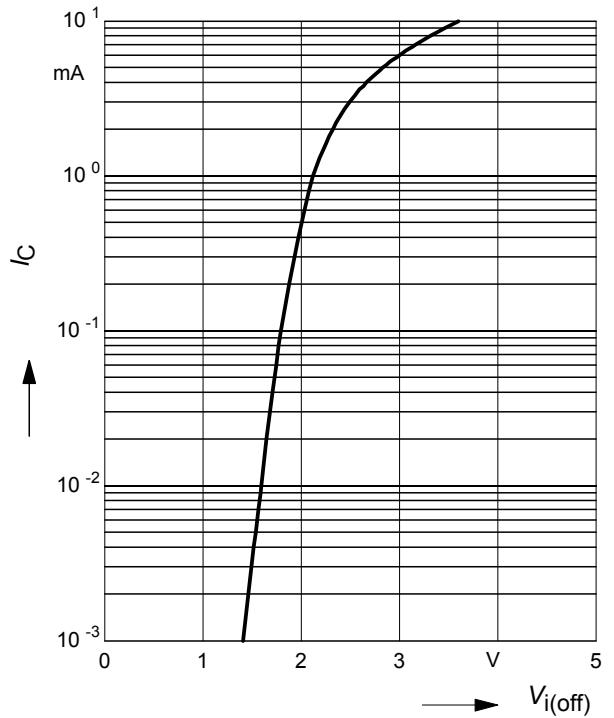
Input on Voltage $V_{i(on)} = f(I_C)$
 $V_{CE} = 0.3V$ (common emitter configuration)



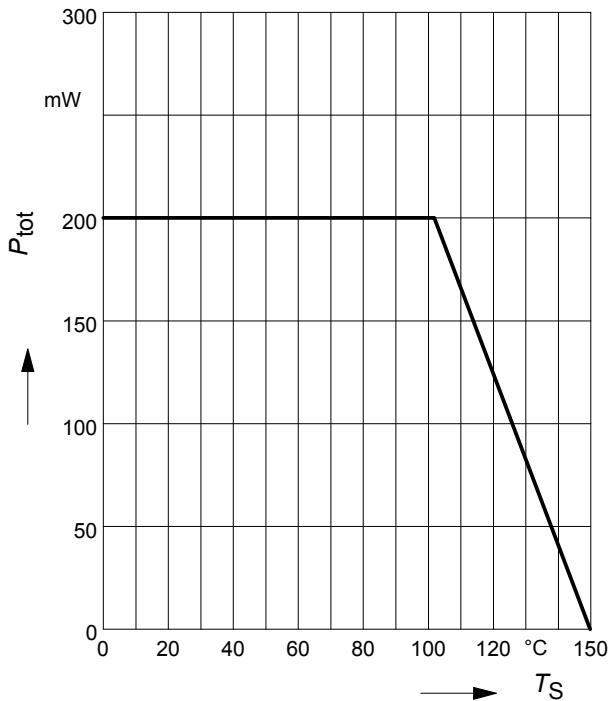
Collector-emitter saturation voltage
 $V_{CEsat} = f(I_C)$, $h_{FE} = 20$



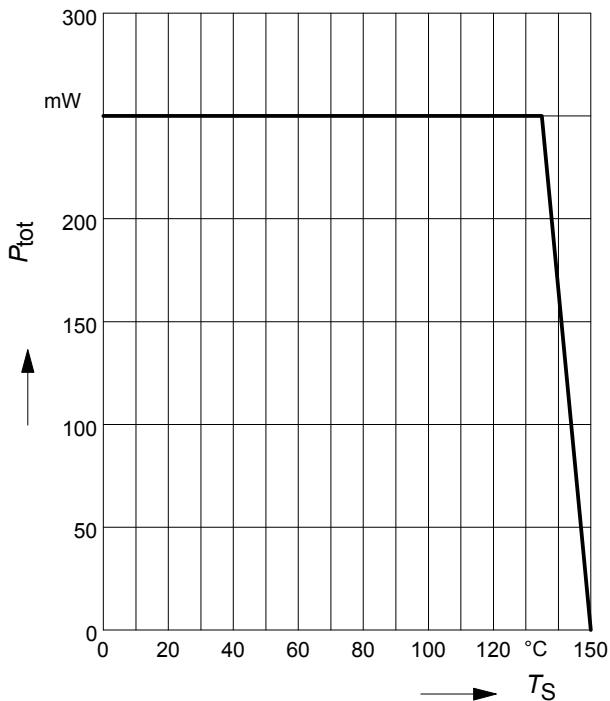
Input off voltage $V_{i(off)} = f(I_C)$
 $V_{CE} = 5V$ (common emitter configuration)



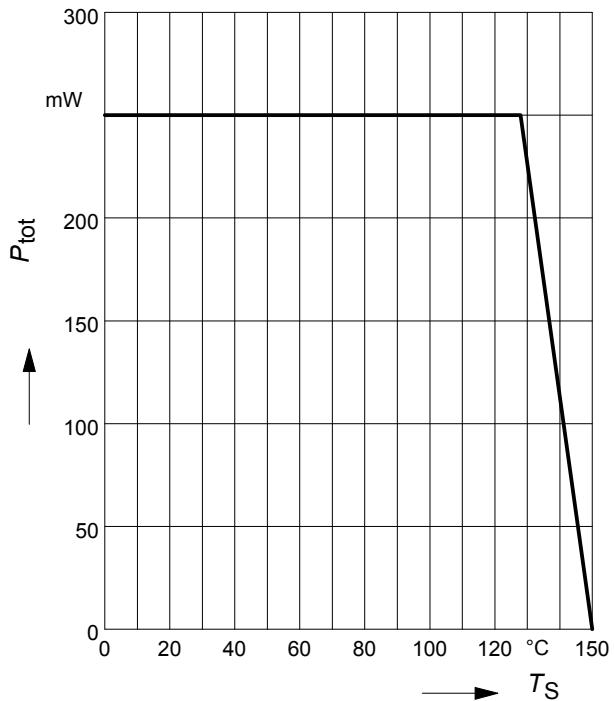
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR146



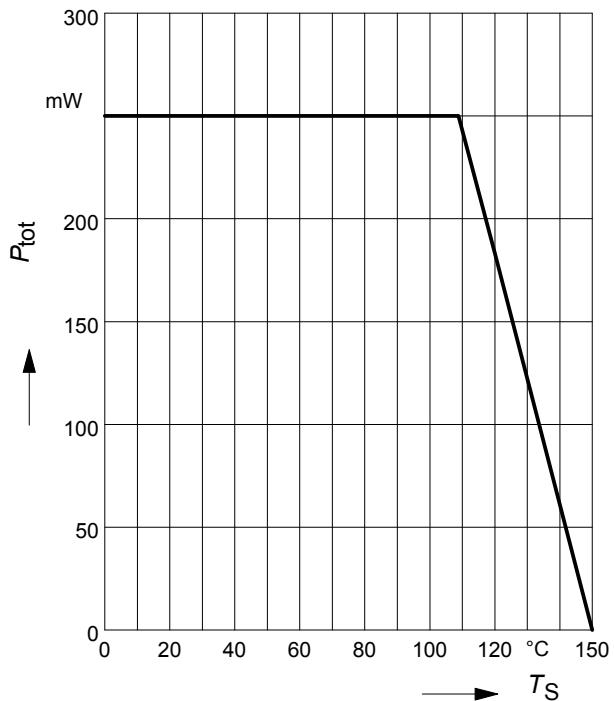
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR146L3



Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR146F

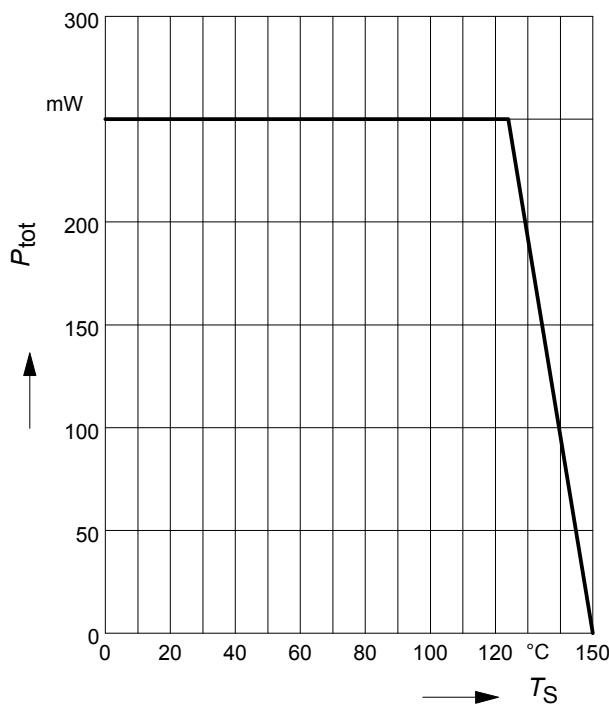


Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR146T



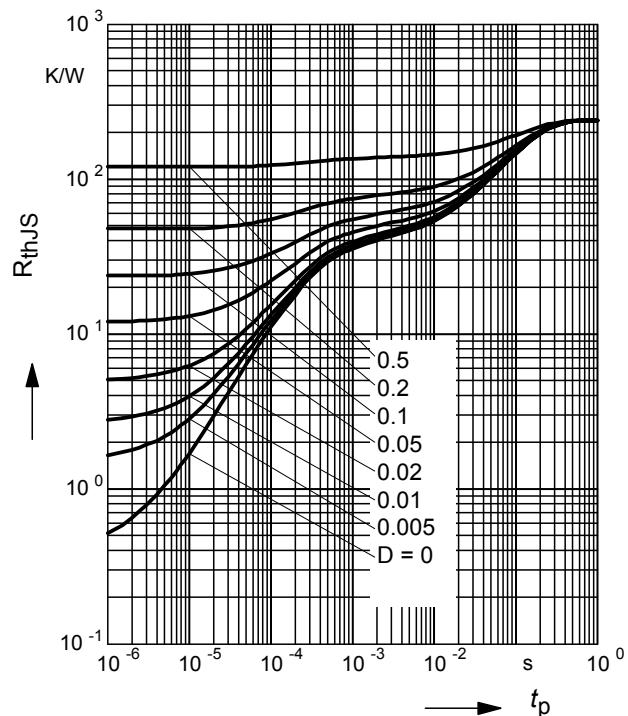
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR146W



Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$

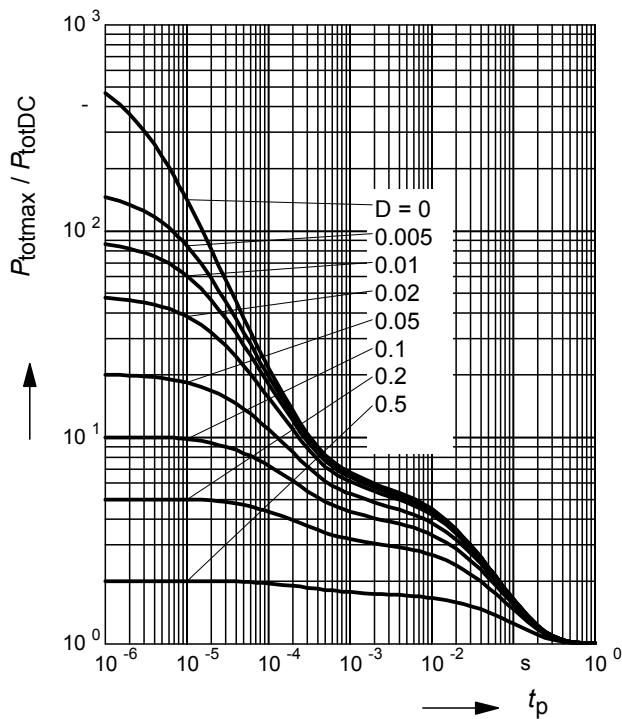
BCR146



Permissible Pulse Load

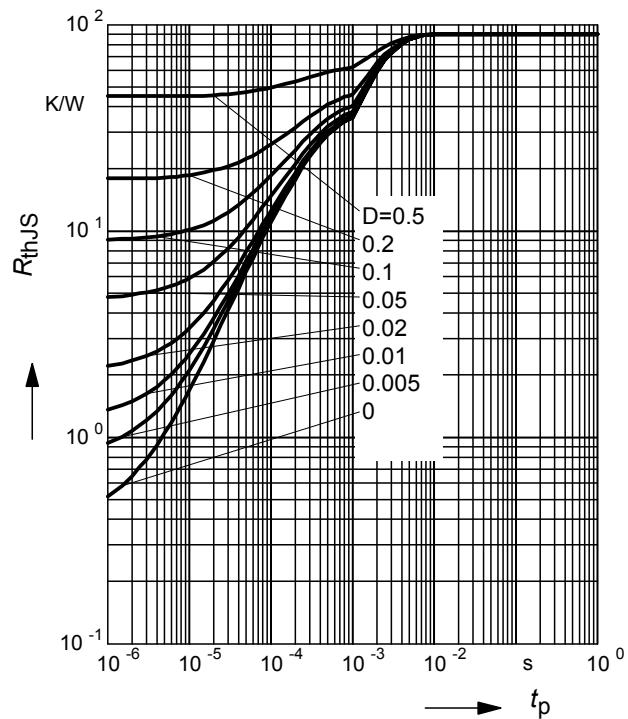
$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

BCR146



Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$

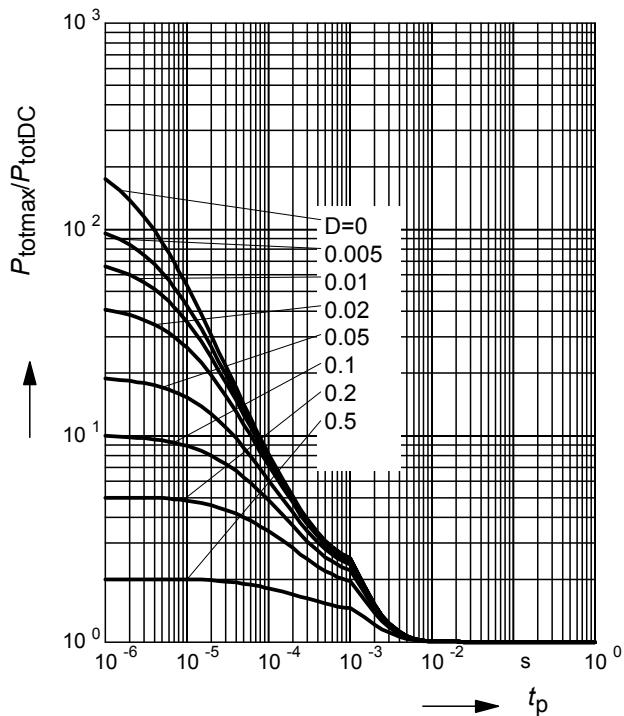
BCR146F



Permissible Pulse Load

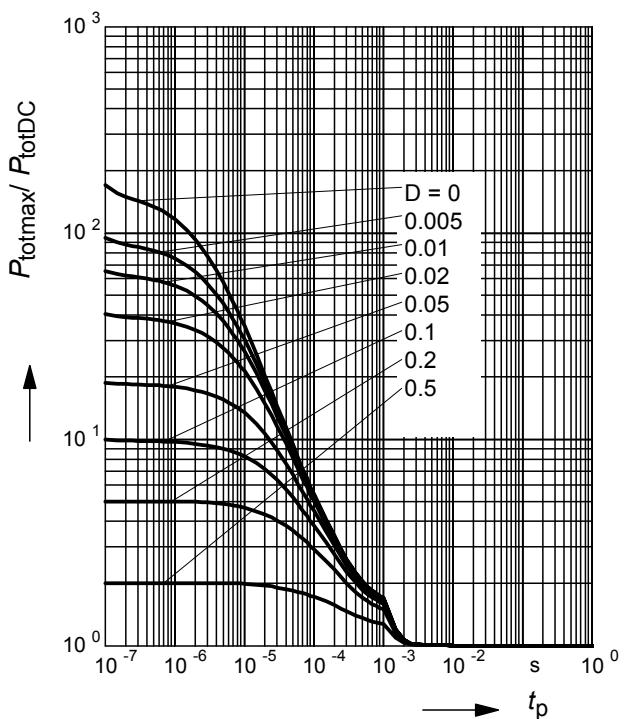
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR146F

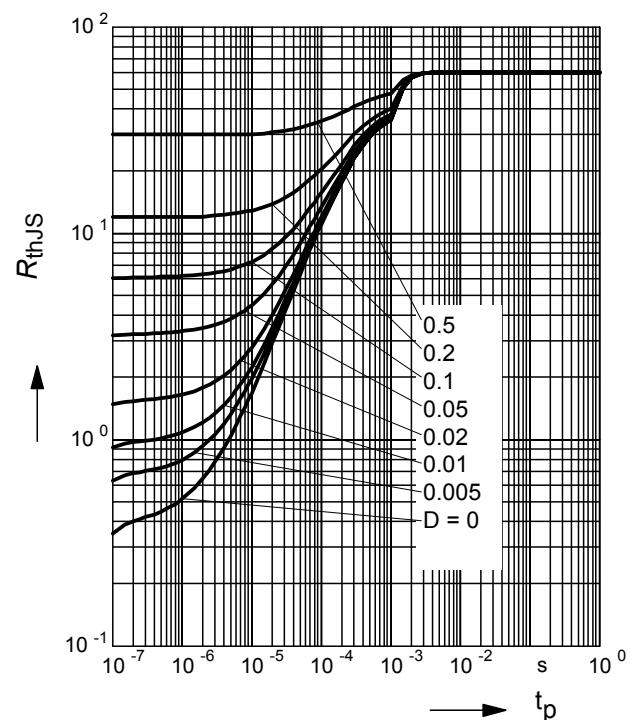

Permissible Pulse Load

$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

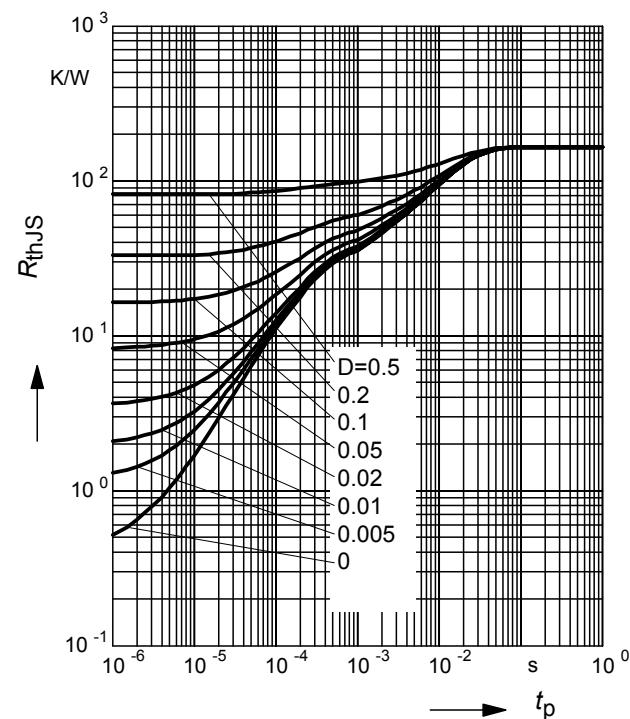
BCR146L3


Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

BCR146L3


Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

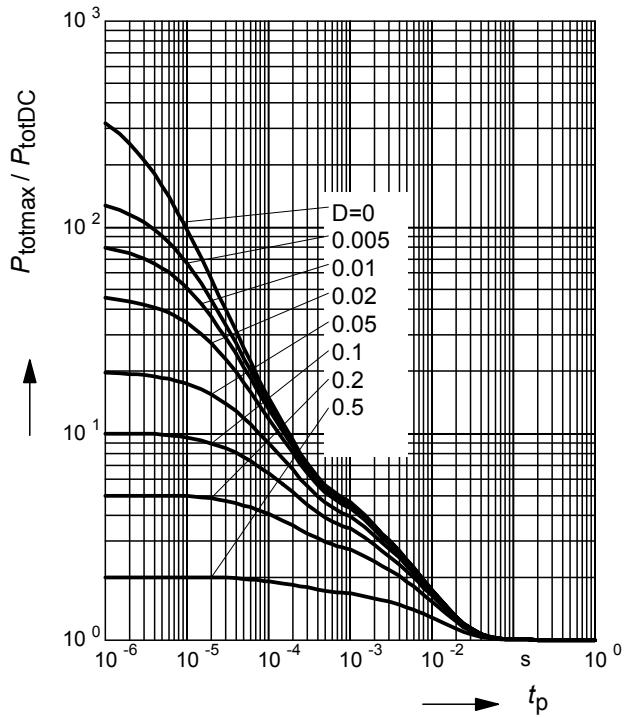
BCR146T



Permissible Pulse Load

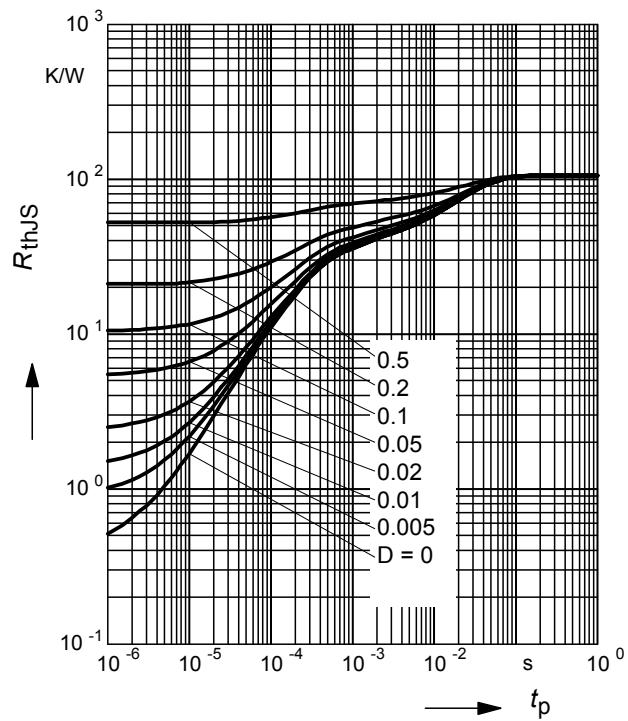
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR146T



Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$

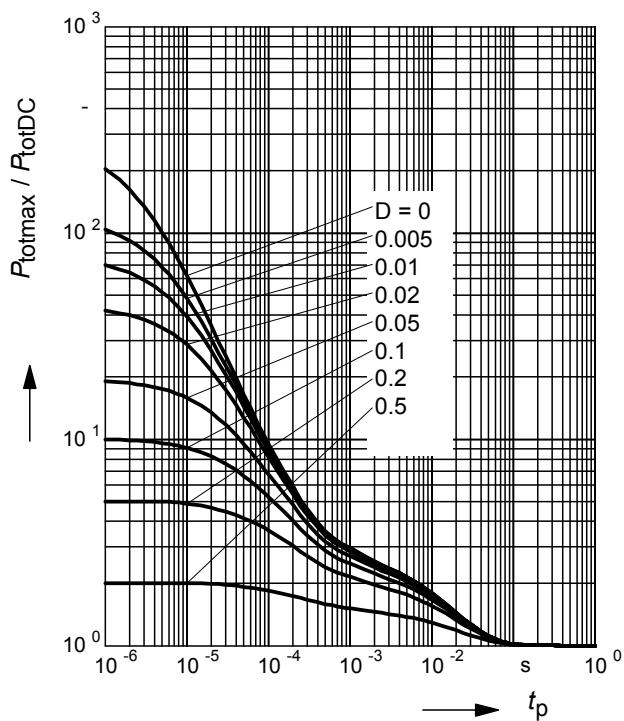
BCR146W



Permissible Pulse Load

$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR146W



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